

## **General Description**

The AAT2803 is a dual charge pump designed to support both white LED backlight and flash applications for systems operating with lithium-ion/polymer batteries. The backlight charge pump is capable of driving up to six LEDs at a total of 180mA. The current sinks may be operated in group or in parallel for driving higher current LEDs. To maximize power efficiency, the charge pump operates in 1X, 1.5X, or 2X mode, where the mode of operation is automatically selected by comparing the forward voltage of each LED with the input voltage. AnalogicTech's AS<sup>2</sup>Cwire™ (Advanced Simple Serial Control<sup>™</sup>) serial digital input is used to enable, disable, and set current for each LED with a 16-level logarithmic scale plus four lowcurrent settings down to 50µA for optimized efficiency, with a low housekeeping current of only 50µA.

The flash charge pump is a charge pump doubler with a regulated output voltage. It is designed to deliver 120mA of continuous current and up to 300mA of pulsed current. It has an independent enable pin for improved power savings.

The AAT2803 is equipped with built-in protection, short-circuit, and auto-disable for load short-circuit condition. Built-in soft-start circuitry prevents excessive inrush current during start-up. A low-current shutdown feature disconnects the load from  $V_{IN}$  and reduces quiescent current to less than 1µA.

The AAT2803 is available in a Pb-free, space-saving, thermally enhanced 24-pin 4x4mm QFN package and is rated over the -40°C to +85°C temperature range.

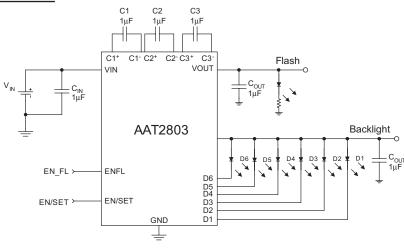
## **Features**

## **ChargePump**<sup>™</sup>

- V<sub>IN</sub> Range: 2.7V to 5.5V
- Dual Charge Pump:
  - Flash: Charge Pump Doubler
  - Backlight: Tri-Mode Charge Pump
- Backlight Charge Pump:
  - Programmable Current With Single GPIO
  - 16 Current Steps
  - 15/20/30mA Max Current
  - Four Low Current Settings
  - Individual Main/Sub-Group Control
  - Low I<sub>Q</sub> (50µA) for Low-Current Mode
  - Drives Six Channels of LEDs
- Flash Charge Pump:
  - Regulated V<sub>OUT\_FL</sub> 4.5/5.0 Volts
     Up to 300mA of Current for Flash
  - 1MHz Constant Switching Frequency
- 1MHz Constant Switching Frequency
   Independent Backlight/Flash Control
- Built-In Thermal Protection
- Built-In Thermal Protection
- Built-In Auto-Disable for Open Circuit
- Automatic Soft Start
- $I_Q < 1\mu A$  in Shutdown
- Available in QFN44-24 Package

## Applications

- Color (RGB) Lighting
- Programmable Current Sink
- White LED Backlighting
- White Photo Flash for Digital Still Cameras



# Typical Application

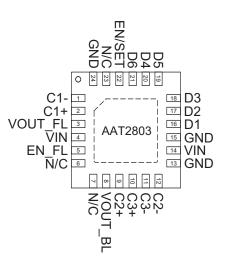


## **Pin Descriptions**

Pin #	Symbol	Function
1	C1-	Flying capacitor 1 negative terminal.
2	C1+	Flying capacitor 1 positive terminal. Connect a 1µF capacitor between C1+ and C1
3	VOUT_FL	Flash output voltage. Requires 1µF capacitor connected between this pin and ground.
4, 14	VIN	Input power supply. Requires 1µF capacitor connected between this pin and ground.
5	EN_FL	Enable pin for flash charge pump. For normal operation, connect to $V_{IN}$ . When connected low, the flash charge pump shuts down and consumes less than 1µA of current.
6, 7, 23	N/C	No connect.
8	VOUT_BL	Backlight output voltage charge pump. Requires 1µF capacitor connected between this pin and ground.
9	C2+	Flying capacitor 2 positive terminal. Connect a 1µF capacitor between C2+ and C2
10	C3+	Flying capacitor 3 positive terminal. Connect a 1µF capacitor between C3+ and C3
11	C3-	Flying capacitor 3 negative terminal.
12	C2-	Flying capacitor 2 negative terminal.
13, 15, 24	GND	Ground.
16	D1	Current sink input #1.
17	D2	Current sink input #2.
18	D3	Current sink input #3.
19	D5	Current sink input #5.
20	D4	Current sink input #4.
21	D6	Current sink input #6.
22	EN/SET	AS <sup>2</sup> Cwire serial interface control pin for backlight charge pump. It controls the current
		settings for all six channels. This pin should not be left floating.
EP		Exposed paddle (bottom); connect to GND directly beneath package.

# **Pin Configuration**







## Absolute Maximum Ratings<sup>1</sup>

Symbol	Description	Value	Units
V <sub>IN</sub>	Input Voltage	-0.3 to 6	V
V <sub>EN/SET</sub>	EN/SET to GND Voltage	-0.3 to V <sub>IN</sub> + 0.3	V
TJ	Operating Junction Temperature Range	-40 to 150	°C
T <sub>LEAD</sub>	Maximum Soldering Temperature (at leads, 10 sec)	300	°C

## **Thermal Information<sup>2</sup>**

Symbol	Description	Value	Units
P <sub>D</sub>	Maximum Power Dissipation <sup>3</sup>	2.0	W
$\theta_{JA}$	Maximum Thermal Resistance		°C/W

<sup>1.</sup> Stresses above those listed in Absolute Maximum Ratings may cause permanent damage to the device. Functional operation at conditions other than the operating conditions specified is not implied. Only one Absolute Maximum Rating should be applied at any one time.

<sup>2.</sup> Mounted on an FR4 board.

<sup>3.</sup> Derate 6.25mW/°C above 25°C.



## **Electrical Characteristics**<sup>1</sup>

 $\overline{V_{IN}}$  = 3.6V,  $C_{IN} = C_{OUT} = C_1 = C_2 = C_3 = 1.0 \mu$ F;  $T_A = -40^{\circ}$ C to +85°C, unless otherwise noted. Typical values are  $T_A = 25^{\circ}$ C.

Symbol	Description	Conditions	Min	Тур	Max	Units	
V <sub>IN</sub>	Operation Range		2.7		5.5	V	
		1X Mode, $3.0 \le V_{IN} \le 5.5$ , Active, No Load Current; EN/SET = $V_{IN}$ ; EN_FL= GND		0.3	1	mA	
	Operating Current	1.5X Mode, $3.0 \le V_{IN} \le 5.5$ , Active, No Load Current; EN/SET = $V_{IN}$ ; EN_FL= GND		1.0	3.0		
I <sub>CC</sub>		2X Mode, $3.0 \le V_{IN} \le 5.5$ , Active, No Load Current; EN/SET = $V_{IN}$ ; EN_FL = GND		2.0	3.7		
		$V_{OUT_{FLASH}}$ = 5V; EN/SET = GND; EN_FL = $V_{IN}$		2.0	4.5		
		50μA Setting, 1X Mode; EN/SET = V <sub>IN</sub> ; EN_FL = GND		50		μA	
I <sub>SHDN</sub>	Shutdown Current	EN/SET = 0			1.0	μA	
I <sub>DX</sub>	I <sub>SINK</sub> Average Current Accuracy <sup>2</sup>	I <sub>SET</sub> = 30mA, T <sub>A</sub> = 25°C	27	30	33	— mA	
'DX		I <sub>SET</sub> = 4.1mA, T <sub>A</sub> = 25°C	3.69	4.1	4.51		
I <sub>(D-Match)</sub>	Current Matching Between Any Two Current Sink Inputs <sup>3,4</sup>	V <sub>F</sub> :D1:D4 = 3.6V		0.5		%	
V <sub>TH</sub>	1X to 1.5X or 1.5X to 2X Transition Threshold at Any $D_X$ Pin			150		mV	
V <sub>OUT</sub>	Output Voltage (Flash Charge Pump)⁵	3.0< V <sub>IN</sub> < 5V, I <sub>OUT</sub> = 120mA; EN_FL = V <sub>IN</sub>	4.3	4.5	4.7	V	
1	Max Continuous Output Current (Flash Charge Pump)⁵	$V_{IN}$ = 3.3V; $V_{OUT}$ = 4.5V; EN_FL = $V_{IN}$	120			mA	
Ι <sub>ΟυΤ</sub>	Max Pulsed Output Current⁵	V <sub>IN</sub> = 3.6V; V <sub>OUT</sub> = 4.5V; I <sub>PULSED</sub> = 250ms		300		mA	
т	Soft-Start Time	Backlight Charge Pump		100		110	
T <sub>SS</sub>		Flash Charge Pump		200		μs	
F <sub>CLK</sub>	Clock Frequency			1.0		MHz	
V <sub>EN(L)</sub>	Enable Threshold Low	V <sub>IN</sub> = 2.7V			0.4	V	
V <sub>EN(H)</sub>	Enable Threshold High	$V_{IN} = 5.5V$	1.4			V	

2. Determined by the average of all active channels.

- 4. Specification applies only to the tri-mode charge pump.
- 5. Specification applies only to the charge pump doubler.

<sup>1.</sup> The AAT2803 is guaranteed to meet performance specifications over the -40°C to +85°C operating temperature range and is assured by design, characterization, and correlation with statistical process controls.

<sup>3.</sup> Current matching is defined as the deviation of any sink current from the average of all active channels.



## **Electrical Characteristics**<sup>1</sup>

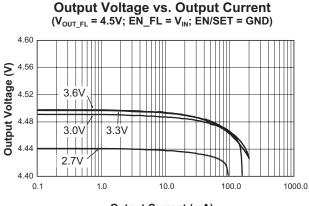
 $V_{IN}$  = 3.6V,  $C_{IN}$  =  $C_{OUT}$  =  $C_1$  =  $C_2$  =  $C_3$  = 1.0µF;  $T_A$  = -40°C to +85°C, unless otherwise noted. Typical values are  $T_A$  = 25°C.

Symbol	Description	Conditions	Min	Тур	Мах	Units
T <sub>EN/SET LO</sub>	EN/SET Low Time		0.3		75	μs
T <sub>EN/SET_HI_MIN</sub>	Minimum EN/SET High Time			50		ns
T <sub>EN/SET_HI_MAX</sub>	Maximum EN/SET High Time				75	μs
T <sub>OFF</sub>	EN/SET Off Timeout				500	μs
T <sub>LAT</sub>	EN/SET Latch Timeout				500	μs
I <sub>EN/SET;EN_FL</sub>	Input Leakage	$V_{EN/SET;EN_FL} = 5V; V_{IN} = 5V$	-1.0		1.0	μA

<sup>1.</sup> The AAT2803 is guaranteed to meet performance specifications over the -40°C to +85°C operating temperature range and is assured by design, characterization, and correlation with statistical process controls.

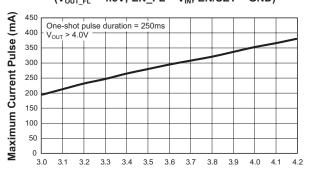


## Typical Characteristics–Flash Driver Charge Pump Section



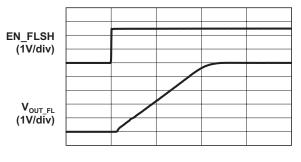
Output Current (mA)

Maximum Current Pulse vs. Supply Voltage (V<sub>OUT\_FL</sub> = 4.5V; EN\_FL = V<sub>IN</sub>; EN/SET = GND)



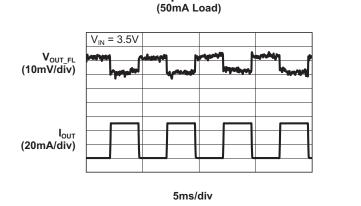
Supply Voltage (V)

Start-Up Time (50mA Load)

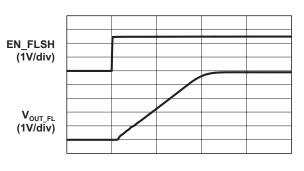


100µs/div

Load Response vs. Time

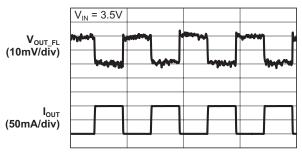


Start-Up Time (100mA Load)



100µs/div

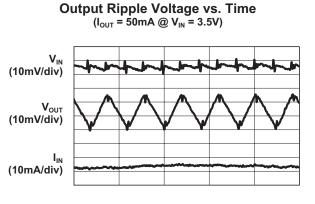




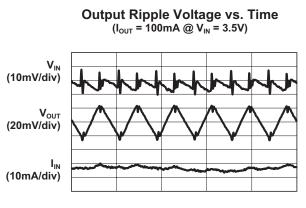
5ms/div



## **Typical Characteristics–Flash Driver Charge Pump Section**

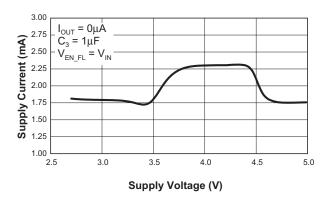


500ns/div

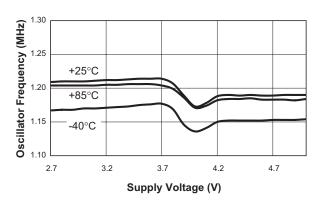


500ns/div

#### Supply Current vs. Supply Voltage



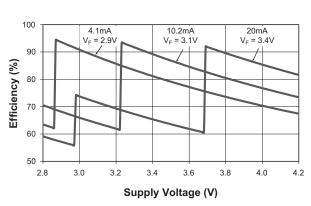
#### **Oscillator Frequency vs. Supply Voltage**





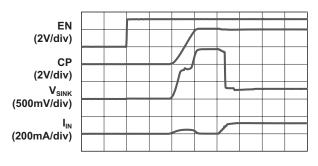
# **Typical Characteristics–White LED Backlight Driver Section**

Unless otherwise noted,  $V_{IN} = 3.6V$ ,  $C_{IN} = C_{OUT} = C_1 = C_2 = C_3 = 1.0 \mu F$ ;  $T_A = 25^{\circ}C$ .



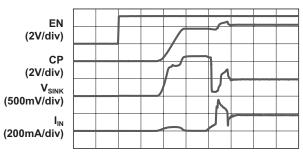
### Efficiency vs. Supply Voltage

Turn-On to 1X Mode (V<sub>IN</sub> = 4.2V; 20mA Load)



100µs/div

Turn-On to 1.5X Mode (V<sub>IN</sub> = 3.8V; 20mA Load)

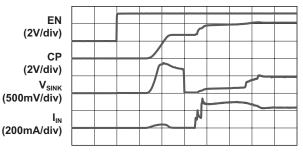


100µs/div

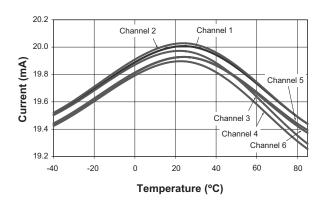
Turn-Off from 1.5X Mode

(V<sub>IN</sub> = 3.5V; 20mA Load)

**Turn-On to 2X Mode** (V<sub>IN</sub> = 2.8V; 20mA Load)

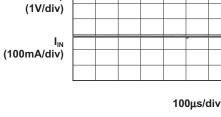


100µs/div



#### Current Matching vs. Temperature

2803.2006.12.1.6

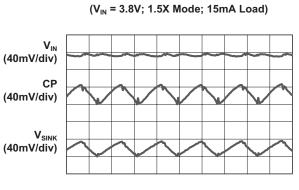


EN (2V/div)

VF



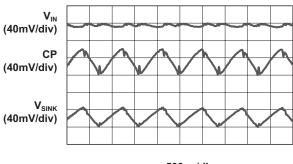
# **Typical Characteristics–White LED Backlight Driver Section** Unless otherwise noted, $V_{IN} = 3.6V$ , $C_{IN} = C_{OUT} = C_1 = C_2 = C_3 = 1.0 \mu$ F; $T_A = 25^{\circ}$ C.



Load Characteristics

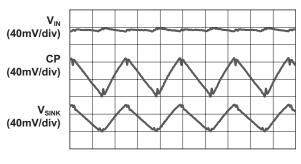
500ns/div

**Load Characteristics** (V<sub>IN</sub> = 4.0V; 1.5X Mode; 20mA Load)



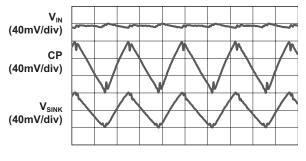
500ns/div

Load Characteristics (V<sub>IN</sub> = 2.9V; 2X Mode; 15mA Load)

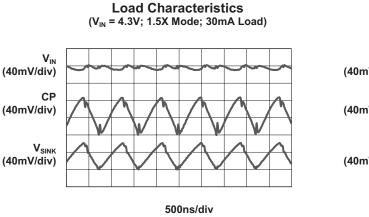


500ns/div

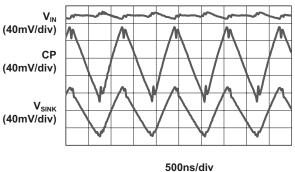
**Load Characteristics** (V<sub>IN</sub> = 3.1V; 2X Mode; 20mA Load)



500ns/div



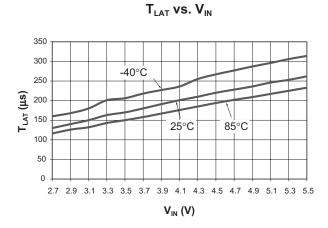
Load Characteristics (V<sub>IN</sub> = 3.6V; 2X Mode; 30mA Load)



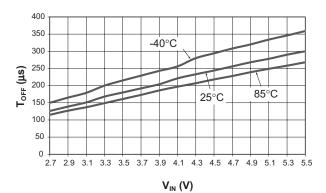
2803.2006.12.1.6



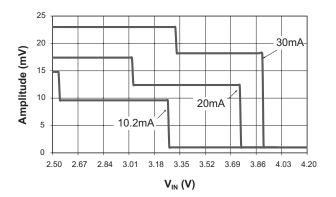
# $\frac{\textbf{Typical Characteristics-White LED Backlight Driver Section}}{\text{Unless otherwise noted, V}_{IN} = 3.6\text{V}, \text{C}_{IN} = \text{C}_{OUT} = \text{C}_1 = \text{C}_2 = \text{C}_3 = 1.0 \mu\text{F}; \text{T}_A = 25^{\circ}\text{C}.}$



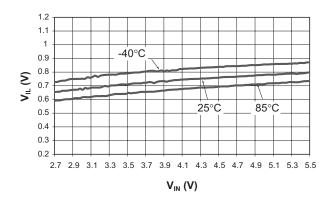
TOFF VS. VIN



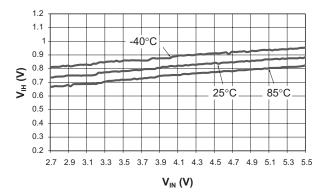
Input Ripple vs. V<sub>IN</sub>





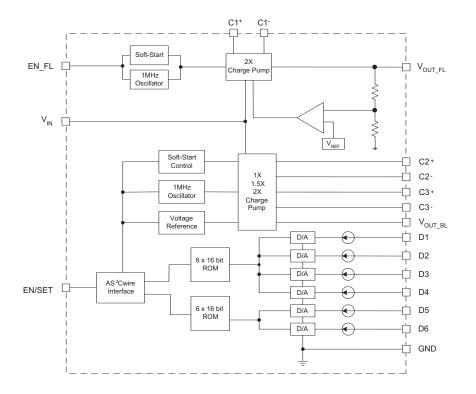


V<sub>IH</sub> vs. V<sub>IN</sub>





## **Functional Block Diagram**



# **Functional Description**

The AAT2803 is a dual charge pump targeted for backlight and flash applications. The charge pump for white LED applications is a tri-mode load switch (1X) and high efficiency (1.5X or 2X) charge pump device. To maximize power conversion efficiency, an internal sensing circuit monitors the voltage required on each constant current sink input and sets the load switch and charge pump modes based on the input battery voltage and the current sink input voltage. As the battery discharges over time, the backlight charge pump is enabled when any of the six current sink inputs near dropout. The charge pump initially starts in 1.5X mode. If the charge pump output drops enough for any current source output to become close to dropout, the charge pump will automatically transition to 2X mode.

For flash applications, charge pump doubler architecture is used to support the high current demand required by the application. Charge pump regulation is achieved by sensing the output voltage through an internal resistor divider network. A switch doubling circuit is enabled when the divided output drops below a preset trip point controlled by an internal comparator. The free-running charge pump switching frequency is approximately 1MHz. The charge pump is designed to deliver 120mA of continuous current and 300mA of pulsed current.

The AAT2803 requires only six external components: three 1µF ceramic capacitors for the charge pump flying capacitors ( $C_1$ ,  $C_2$ , and  $C_3$ ), one 1µF ceramic input capacitor ( $C_{IN}$ ), one 0.33µF to 1µF ceramic capacitor for the backlight charge pump output, and one 1µF for the flash charge pump output. The six constant current sink inputs (D1 to D6) can drive six individual LEDs with a maximum current of 30mA each. The unused sink inputs must be connected to  $V_{OUT BL}$ , otherwise the part will operate only in 2X charge pump mode. The AS<sup>2</sup>Cwire serial interface enables the backlight charge pump and sets the current sink magnitudes. AS<sup>2</sup>Cwire addressing allows independent control of two groups of current sink input: D1 to D4 and D5 to D6.



### **Constant Current Output Level Settings**

The constant current sink levels for the white LED backlight (D1 to D6) are set via the serial interface according to a logarithmic scale where each code is 1dB lower than the previous code. In this manner, LED brightness appears linear with each increasing code count. Because the inputs D1 to D6 are true independent constant current sinks, the voltage observed on any single given input will be determined by the actual forward voltage (V<sub>F</sub>) for the LED being driven.

Since the input current sinks are programmable, no PWM (pulse width modulation) or additional control circuitry is needed to control LED brightness. This feature greatly reduces the burden on a microcontroller or system IC to manage LED or display brightness, allowing the user to "set it and forget it." With its highspeed serial interface (1MHz data rate), the input sink current can be changed successively to brighten or dim LEDs in smooth transitions (e.g., to fade-out) or in abrupt steps, giving the user complete programmability and real-time control of LED brightness.

The 16 individual current level settings are each approximately 1dB apart (see Current Level Settings table). Code 1 is full scale, Code 15 is full scale attenuated by 14dB, and Code 16 is reserved as a "no current" setting.

Data	30mA Max I <sub>OUT</sub> (mA)	20mA Max I <sub>OUT</sub> (mA)	15mA Max I <sub>OUT</sub> (mA)
1	30.0	20.0	15.0
2	26.7	17.8	13.3
3	23.8	15.9	11.9
4	21.4	14.3	10.7
5	19.0	12.7	9.5
6	16.7	11.1	8.3
7	15.2	10.2	7.6
8	13.3	8.9	6.7
9	11.9	7.9	6.0
10	10.5	7.0	5.2
11	9.5	6.3	4.8
12	8.6	5.7	4.3
13	7.6	5.1	3.8
14	6.7	4.4	3.3
15	6.2	4.1	3.1
16	0.0	0.0	0.0

 Table 1: Current Level Settings.

#### AS<sup>2</sup>Cwire Serial Interface

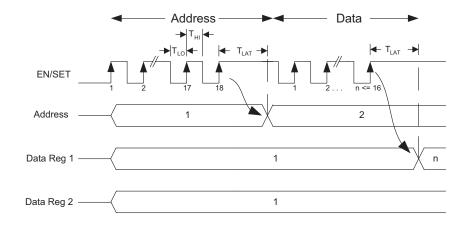
The Advanced Simple Serial Control (AS<sup>2</sup>Cwire) single wire interface is used to set the possible combinations of current levels and LED channel states. AS<sup>2</sup>Cwire has addressing capability for multiple data registers. With multiple data registers, the backlight charge pump main and sub-channels can be programmed together or independently from one another.

AS<sup>2</sup>Cwire relies on the number of rising edges of the EN/SET pin to address and load the registers. AS<sup>2</sup>Cwire latches data or address after the EN/SET pin has been held high for time  $T_{IAT}$ . Address or data is differentiated by the number of EN/SET rising edges. Since the data registers are 4 bits each, the differentiating number of pulses is 2<sup>4</sup> or 16, so that Address 1 is signified by 17 rising edges, Address 2 by 18 rising edges, and so forth. Data is set to any number of rising edges between 1 and including 16. A typical write protocol is a burst of EN/SET rising edges, signifying a particular Address, followed by a pause with EN/SET held high for the T<sub>I AT</sub> timeout period, a burst of rising edges signifying Data, and a T<sub>LAT</sub> timeout for the data registers. Once an address is set, then multiple writes to the corresponding data register are allowed.

When EN/SET is held low for an amount of time greater than  $T_{OFF}$ , the backlight charge pump enters into shutdown mode and draws less than 1µA from the supply. Address 1 is the default address on the first rising edge after the backlight charge pump has been disabled. Whenever shutdown mode is entered, all registers are reset to 1.



## AS<sup>2</sup>Cwire Serial Interface Timing



## AS<sup>2</sup>Cwire Addressing

Five addresses are available to enable all of the part's functionality. Two 4-bit registers control the main and sub-channels, giving 16 settings for each. The main and sub-channels are programmed to the same constant current level by using Address 1. Use Addresses 2 and 3 to program the main and sub-channels independently. Use Address 4 to program the Max Current register, which sets the Max Current scale. Lastly, Address 5 programs the Low Current register. The Low Current register controls the efficient Low Current mode. When the Max Current register is programmed to 1, 2, or 3, changing the data for Addresses 1-3 will result in the corresponding values found in the Constant Current Programming Levels table.

When the Max Current register is programmed to 4, the part is programmed to operate in Low Current mode and the Data for Addresses 1-3 is irrelevant. In Low Current mode, the Low Current register takes precedence. See the Low Current Register Settings table below for the current level settings and main/sub-configurations that result.

Address	EN/SET Edges	Addressed Register
1	17	1&2: D1-D6
		Current
2	18	1: D1-D4 Current
3	19	2: D5-D6 Current
4	20	3: Max Current
5	21	4: Low Current

#### Max Current and Low Current Registers

Use the Max Current and Low Current registers to program constant current settings outside of the 20mA Max scale. By default (without changing the Max Current register), the backlight charge pump operates in the 20mA Max scale (see Constant Current Programming Levels). For example, to change to the 30mA Max scale, address the Max Current register with 20 rising edges and pause for  $T_{I \Delta T}$ . Program the Max Current register with 2 rising edges and pause for TLAT. The part will next operate in the same Data row, but for the setting found in the 30mA Max column. Next, to change to a different setting on the 30mA Max scale, address the D1-D6 register with 17 rising edges. Program the new constant current level with 1-16 rising edges. The part will update to the new Data setting according to the Constant Current Programming Levels table.

The backlight charge pump has a distinct Low Current mode with ultra-low quiescent current. For drive currents of 2mA or less, the part operates with significantly reduced quiescent current. This is particularly useful for applications requiring an "always on" condition such as transmissive displays. As an example, to change to Low Current mode, address the Max Current register with 20 rising edges and pause for  $T_{LAT}$ . Program the Max Current register with 4 rising edges and pause for  $T_{LAT}$ . Program the Low Current register with 1-16 rising edges. The part will update to the new Low Current mode setting and operate with significantly reduced quiescent current.



#### Max Current Register Settings—Address 4

Data	Max Current
1	20mA Max Scale
2	30mA Max Scale
3	15mA Max Scale
4	Low Current Mode

#### Low Current Register Settings—Address 5

Data	D1-D4 (mA)	D5-D6 (mA)
1	0	0
2	0	0
3	0	0
4	0	0
5	0	0.05
6	0	0.5
7	0	1
8	0	2
9	0.05	0
10	0.5	0
11	1	0
12	2	0
13	0.05	0.05
14	0.5	0.5
15	1	1
16	2	2

### **Disabled Current Sinks**

The backlight charge pump is equipped with an autodisable feature to protect against an LED failure condition. Current sink inputs that are not used should be disabled. To disable and properly terminate unused current sink inputs, they must be tied to  $V_{OUT}$ . If left unconnected or terminated to ground, the part will be forced to operate in 2X charge pump mode.

Properly terminating unused current sink inputs is important to prevent the charge pump modes from activating prematurely. When properly terminated, only a small sense current flows for each disabled channel. The sense current for each disabled channel is less than  $120\mu$ A.

## **Applications Information**

#### **LED Selection**

Although the AAT2803 is specifically intended for driving white LEDs, the device can also be used to drive most types of LEDs with forward voltage specifications ranging from 2.0V to 4.7V. LED applications may include main and sub-LCD display backlighting, camera photo-flash applications, color (RGB) LEDs, infrared (IR) diodes for remotes, and other loads benefiting from a controlled output current generated from a varying input voltage.

In some instances (e.g., in high-luminous-output applications such as photo flash), it may be necessary to drive high- $V_F$  type LEDs. The low-dropout current sinks in the AAT2803 make it capable of driving LEDs with forward voltages as high as 4.7V at full current from an input supply as low as 3.0V. Outputs can be paralleled to drive high-current LEDs without complication.

### **Device Switching Noise Performance**

The AAT2803 operates at a fixed frequency of approximately 1MHz to control noise and limit harmonics that can interfere with the RF operation of cellular telephone handsets or other communication devices. Back-injected noise appearing on the input pin of the charge pump is 20mV peak-topeak, typically ten times less than inductor-based DC/DC boost converter white LED backlight solutions. The AAT2803 soft-start feature prevents noise transient effects associated with inrush currents during start-up of the charge pump circuit.

### **Capacitor Selection**

Careful selection of the six external capacitors  $C_{IN}$ ,  $C_1$ ,  $C_2$ ,  $C_3$ , and  $C_{OUT}$  (for backlight and flash) is important because they will affect turn-on time, output ripple, and transient performance. Optimum performance will be obtained when low equivalent series resistance (ESR) ceramic capacitors are used. In general, low ESR may be defined as less than 100m $\Omega$ . A value of 1µF for all four capacitors is a good starting point when choosing capacitors. If the LED current sources are only programmed for light current levels, then the capacitor size may be decreased.



### **Capacitor Characteristics**

Ceramic composition capacitors are highly recommended over all other types of capacitors for use with the AAT2803. Ceramic capacitors offer many advantages over their tantalum and aluminum electrolytic counterparts. A ceramic capacitor typically has very low ESR, is lowest cost, has a smaller PCB footprint, and is non-polarized. Low ESR ceramic capacitors help maximize charge pump transient response. Since ceramic capacitors are non-polarized, they are not prone to incorrect connection damage.

### **Equivalent Series Resistance**

ESR is an important characteristic to consider when selecting a capacitor. ESR is a resistance internal to a capacitor that is caused by the leads, internal connections, size or area, material composition, and ambient temperature. Capacitor ESR is typically measured in milliohms for ceramic capacitors and can range to more than several ohms for tantalum or aluminum electrolytic capacitors.

#### **Ceramic Capacitor Materials**

Ceramic capacitors less than  $0.1\mu$ F are typically made from NPO or C0G materials. NPO and C0G materials typically have tight tolerance and are stable over temperature. Larger capacitor values are typically composed of X7R, X5R, Z5U, or Y5V dielectric materials. Large ceramic capacitors, typically greater than 2.2µF, are often available in lowcost Y5V and Z5U dielectrics, but capacitors greater than 1µF are not typically required.

Capacitor area is another contributor to ESR. Capacitors that are physically large will have a lower ESR when compared to an equivalent material smaller capacitor. These larger devices can improve circuit transient response when compared to an equal value capacitor in a smaller package size.



## **Ordering Information**

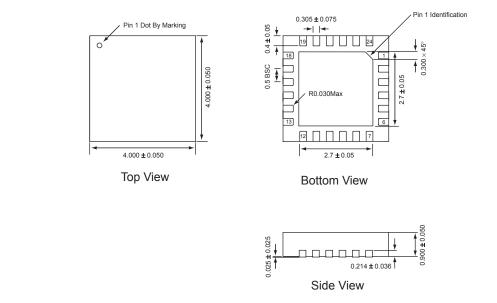
Package	<b>Marking</b> <sup>1</sup>	Part Number (Tape and Reel) <sup>2</sup>
QFN44-24	OFXYY	AAT2803ISK-4.5-T1



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## Package Information<sup>3</sup>

QFN44-24



All dimensions in millimeters.

- 1. XYY = assembly and date code.
- 2. Sample stock is generally held on part numbers listed in BOLD.
- 3. The leadless package family, which includes QFN, TQFN, DFN, TDFN and STDFN, has exposed copper (unplated) at the end of the lead terminals due to the manufacturing process. A solder fillet at the exposed copper edge cannot be guaranteed and is not required to ensure a proper bottom solder connection.

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